

Supporting information

Double-shelled support and confined void strategy for improving lithium storage properties of SnO₂/C anode materials for lithium-ion batteries

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Comparing the TEM images of $\text{SiO}_2@\text{PR}@\text{SiO}_2$ and $\text{PR}@\text{SnO}_2@\text{PS}$, it can be clearly seen that SnO_2 coating, polysaccharides coating and SiO_2 template removal are achieved simultaneously during hydrothermal treatment.

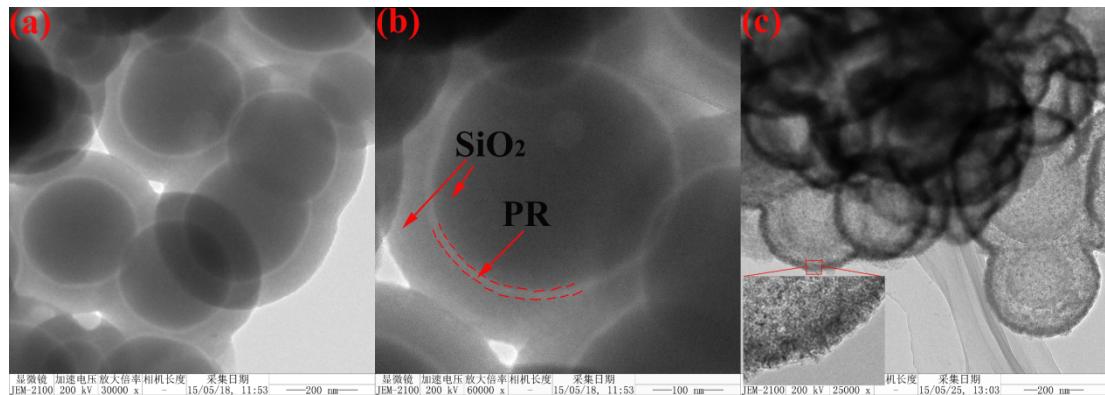


Figure S1. TEM images of $\text{SiO}_2@\text{PR}@\text{SiO}_2$ (a, b) and $\text{PR}@\text{SnO}_2@\text{PS}$ (c).

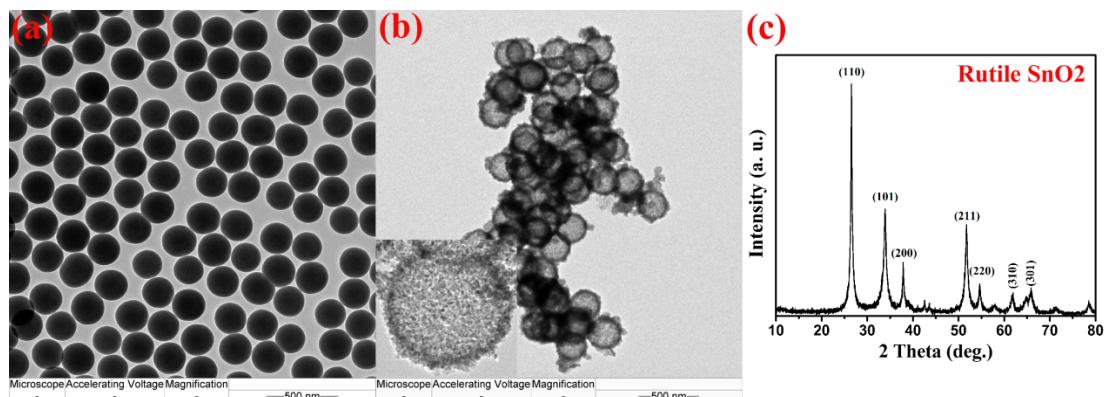


Figure S2. TEM images of SiO_2 templates (a) and SnO_2 HS (b). XRD patterns of SnO_2 HS (c)

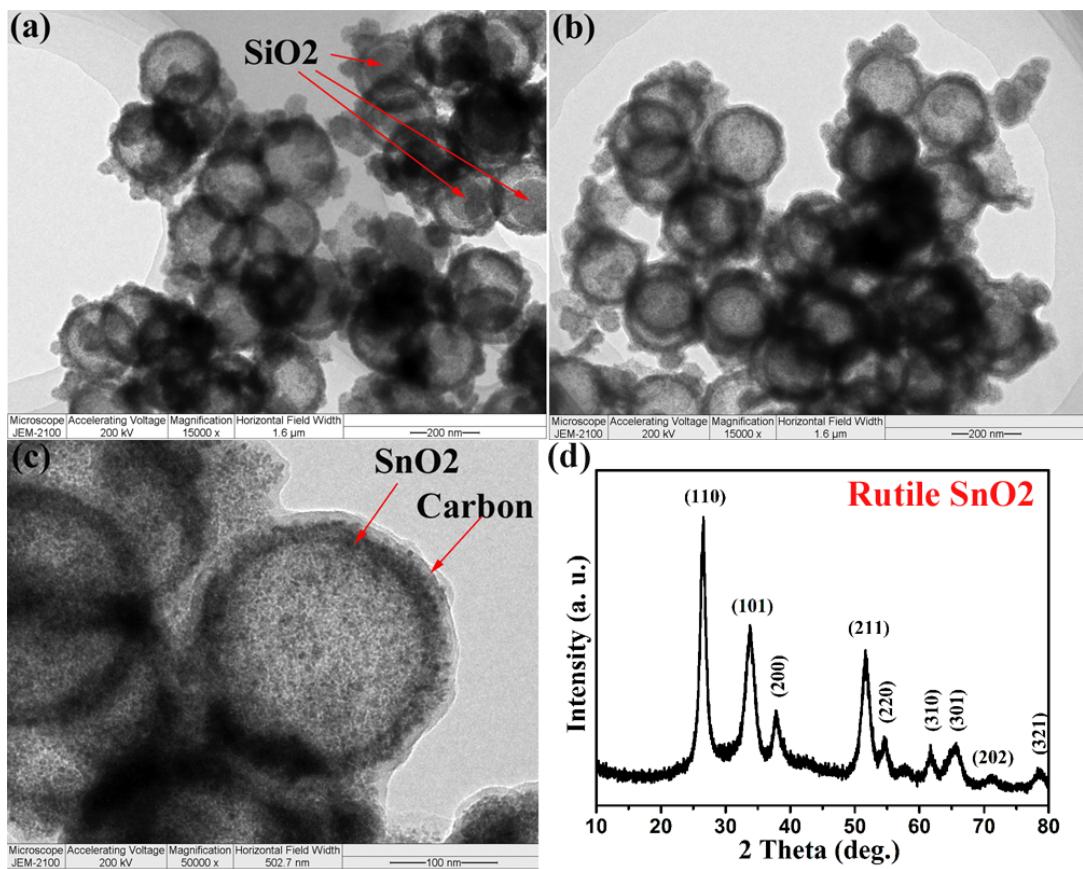


Figure S3. TEM images of SnO_2 @SSC-24 (a) and SnO_2 @SSC (hydrothermal treatment for 48 h) (b, c). XRD patterns of SnO_2 @SSC HS (d).

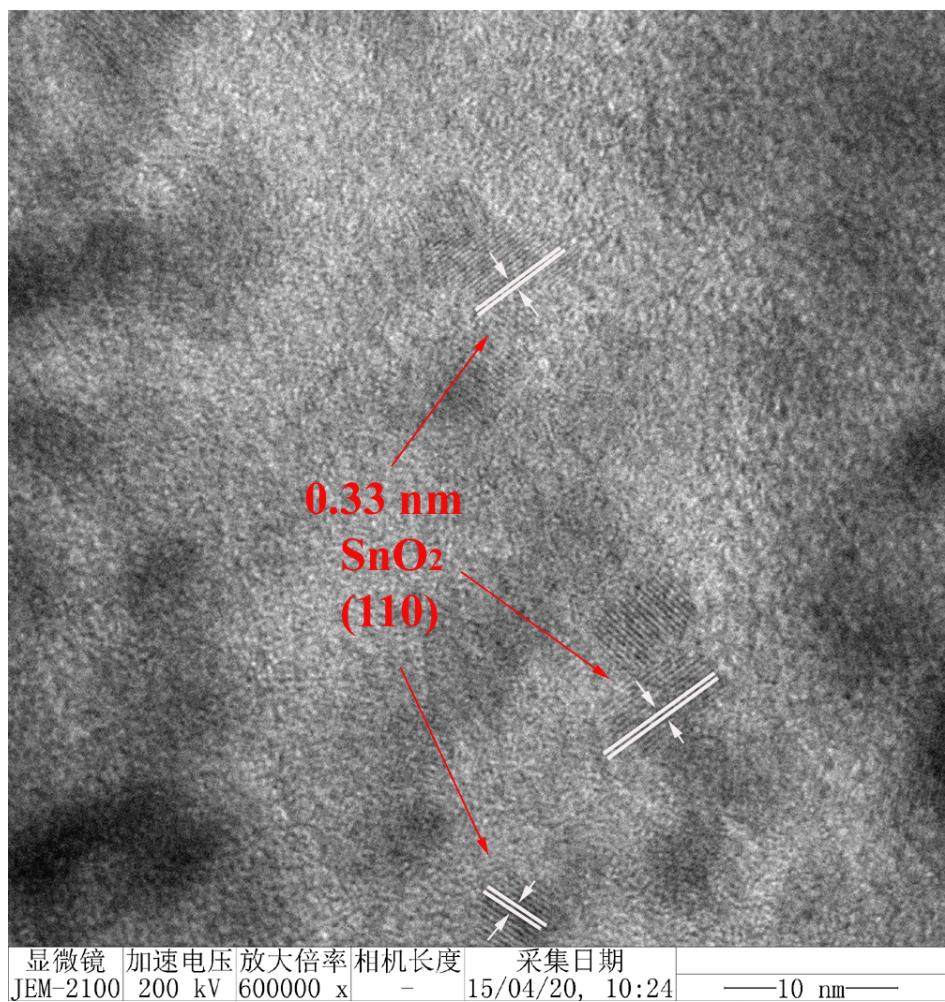


Figure S4. The HRTEM image of outer shell of $\text{SnO}_2@\text{DSC}$

Table S1. Comparison of our product SnO₂@DSC with SnO₂/C-based anode materials reported in other literatures.

SnO ₂ /C-based anode materials	Potential cutoff (V)	Current density (mA g ⁻¹)	Cycles	Capacity (mA h g ⁻¹)	Reference
SnO₂@DSC	3-0.01	200	500	838.2	This work
Sn/SnO ₂ /AMCMB	2.2-0	100	50	451	1
Double shelled hollow SnO ₂ /P	2.5-0.01	200	430	711.9	2
SnO ₂ @OMC	3-0.01	100	60	769	3
SnO ₂ /CNTs-30	1.5-0.01	100	300	430	4
SnO ₂ /C-10	2.5-0.01	100	70	720	5
SnO ₂ @C nanocluster	2.5-0.01	100	200	1215	6
SnO ₂ -HNS/G	3-0.005	500	300	696	7
SnO ₂ /GAs	3-0.05	50	50	760	8
SnO ₂ -CMK-5	3-0.01	178	30	598	9
Carbon-coated SnO ₂ nanotubes	2-0.01	100	50	400	10
SnO ₂ /C	2.5-0.05	300	350	653	11
CNTs@SnO ₂ @C	2-0.01	100	65	462.5	12
SnO ₂ HPNFs	3-0.01	100	50	583	13
SnO ₂ HPNTs	3-0.01	100	50	645	13
SWNTS@SnO ₂ @PPy	3-0.05	150	100	823	14
SnO ₂ /Graphene	1.5-0.005	100	20	433	15
SnO ₂ NSs-graphene	1.2-0.01	400	50	518	16
SnO ₂ NPs in CNTs	2.5-0.005	50	50	560	17
SnO ₂ /SWCNHs	3-0.05	500	180	530	18
SnO ₂ @C nanochains	2-0.005	300	100	646	19
SnO ₂ /mesoporous carbon	2-0.01	100	50	473	20
SnO ₂ @C yolk-shell	3-0	100	100	630	21
RHC-SnO ₂ -C	2-0.05	50	80	525	22
Dense SnO ₂ /C	3-0	100	50	630	23
SnO ₂ on PANI@RGO	3-0.001	0.2C	50	573.6	24
SnO ₂ nanorods/GS	3-0	300	50	574.6	25
SnO ₂ /GNS	2-0.05	50	30	570	26
MWCNT/SnO ₂	3-0	156	100	420	27
SnO ₂ -80@CMK-5	3-0.005	400	100	1004	28
SnO ₂ /graphene	2-0.005	0.2 C	100	550	29
SnO ₂ NSs-array film	1.2-0.01	391	50	674.9	30
Reduced GO/SnO ₂	3-0.01	100	200	718	31
SnO ₂ @C/graphene	3-0.01	100	50	1015	32
SnO ₂ /C hollow spheres	2-0.005	100	50	473	33
SnO ₂ / PEDOT:PSS together with rGO	3-0.005	80	160	980	34

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